NSN 5961-00-469-9984

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-469-9984 **Inclosure Material:** Metal **Overall Length:** 2.257 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 transistor **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.510 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 90.0 collector to base voltage/static/emitter open all transistor and 80.0 collector to emitter voltage/static/base open all transistor and 8.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 2.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Weapon system essential; transistor junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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